## NSN 5962-01-372-1264

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view Online at https://aerobasegroup.com/hsn/5962-01-372-1264
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
0.217 inches
Maximum Power Dissipation Rating:
300.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/disable and w/enable and w/inhibit and high impedance and ultraviolet erasable and programmed and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
17 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
100.00 microamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.6 volts power source and 6.25 volts power source
Capitance Rating Per Characteristic:
10.00 input picofarads and 14.00 output picofarads
Time Rating Per Chacteristic:
200.00 nanoseconds access
Memory Device Type:
Eprom
Test Data Document:
96906-mil-std-883  standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit

N/a

Shelf Life:

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Demilitarization:

Yes - demil/mli

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